

MDL-NS-637/1~200mW



**NANOSECOND PULSED RED DIODE LASER AT 637nm**

This series laser products with excellent material removal rate, are widely used in microelectronics, material processing, solar energy and medical equipment manufacturing, etc.

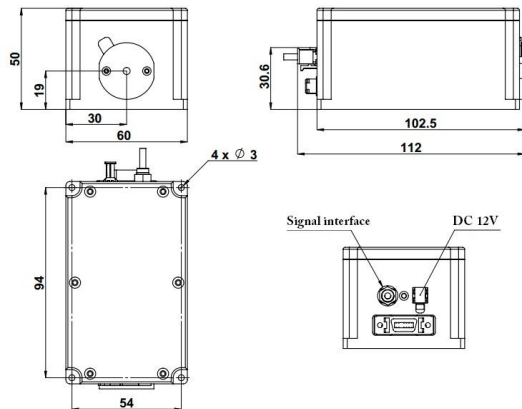


SPECIFICATIONS

Central wavelength (nm)	637±5	
Output power@3.3VDC (mW, CW)	>1, 10, 20, ...,100	>100, 110, ...,200
	Power adjustable by software	
Power stability (rms, over 4 hours)	<3%, <2%, <1%	
Pulse width (FWHM)	>10ns, 20ns, ...,10ms	>10ns, 20ns, ...,10ms
Transverse mode	Near TEM <sub>00</sub>	
Noise of amplitude(rms, CW)	<1%	
M <sup>2</sup> factor	<1.2	
Beam diameter at the aperture (1/e <sup>2</sup> ,mm)	~1.2	
Beam divergence, full angle (mrad)	<1.0	
Polarization ratio	>50:1 (>100:1, optional) Horizontal±5 degree (Vertical Optional)	
User trigger frequency (Multifunctional Pulse Trigger optional)	1Hz-40MHz	1Hz-25MHz
	1Hz-25MHz by using CNI Multifunctional Pulse Trigger	
Rise Time (ns)	<4	<10
Fall Time (ns)	<3	<3
Modulation Depth (extinction ratio)	>1000000:1	
Warm-up time (minutes)	<5	
Beam height from base plate (mm)	19	
Operating temperature (°C)	10~35	
Input voltage	+12VDC	
Expected lifetime (hours)	10000	
Warranty	1 year	

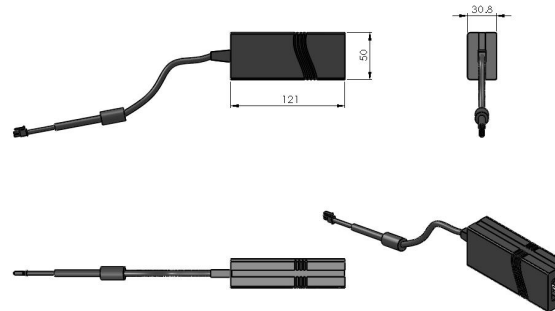


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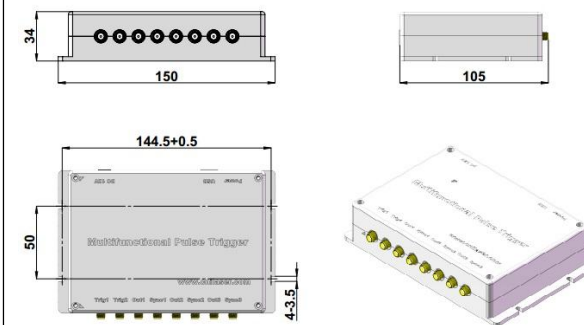
112(L) × 60(W) × 50(H) mm<sup>3</sup>, 0.5kg

Optional Power Supply



121(L) × 50(W) × 30.8 (H) mm<sup>3</sup>, 0.3kg

Multifunctional Pulse Trigger



150(L) × 105(W) × 34(H) mm<sup>3</sup>, 0.5kg